



#### EMS13 H H A -14.318M

Series — RoHS Compliant (Pb-free) 4 Pad 5mm x 7mm SMD 3.3Vdc LVCMOS MEMS Spread Spectrum Oscillator

Frequency Tolerance/Stability ±50ppm Maximum over -40°C to +85°C

Output Control Function

Tri-State (Disabled Output High Impedance)

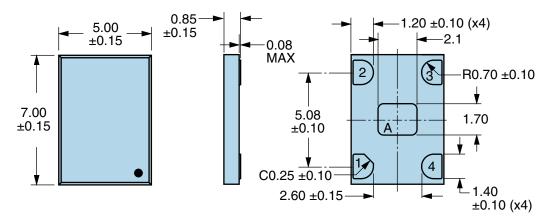
Nominal Frequency 14.318MHz • Spread Spectrum ±0.25% Center Spread

ELECTRICAL SPECIFICATIONS		
Nominal Frequency	14.318MHz	
Frequency Tolerance/Stability	±50ppm Maximum over -40°C to +85°C (Inclusive of all conditions: Calibration Tolerance at 25°C, Frequency Stability over the Operating Temperature Range, Supply Voltage Change, Output Load Change, First Year Aging at 25°C, 260°C Reflow, Shock, and Vibration)	
Aging at 25°C	±1ppm Maximum First Year	
Supply Voltage	3.3Vdc ±10%	
Maximum Supply Voltage	-0.5Vdc to +3.65Vdc	
Input Current	30mA Maximum (Unloaded; Nominal Vdd)	
Output Voltage Logic High (Voh)	90% of Vdd Minimum (IOH=-8mA)	
Output Voltage Logic Low (Vol)	10% of Vdd Maximum (IOL=+8mA)	
Rise/Fall Time	2nSec Maximum (Measured from 20% to 80% of waveform)	
Duty Cycle	50 ±5(%) (Measured at 50% of waveform)	
Load Drive Capability	15pF Maximum	
Output Logic Type	CMOS	
Output Control Function	Tri-State (Disabled Output High Impedance)	
Tri-State Input Voltage (Vih and Vil)	70% of Vdd Minimum or No Connection to Enable Output, 30% of Vdd Maximum to Disable Output	
Disable Current	20mA Maximum (Disabled Output: High Impedance) (Pad 1=Ground)	
Spread Spectrum	±0.25% Center Spread	
Modulation Frequency	30kHz Minimum, 32kHz Typical, 35kHz Maximum	
Period Jitter	30pSec Maximum (Cycle to Cycle; Spread Spectrum-On; Fo=133.333M, Vdd=3.3Vdc)	
Start Up Time	10mSec Maximum	
Storage Temperature Range	-55°C to +125°C	

ENVIRONMENTAL & MECHANICAL SPECIFICATIONS		
ESD Susceptibility	MIL-STD-883, Method 3015, Class 2, HBM 2000V	
Flammability	UL94-V0	
Mechanical Shock	MIL-STD-883, Method 2002, Condition G, 30,000G	
Moisture Resistance	MIL-STD-883, Method 1004	
Moisture Sensitivity Level	J-STD-020, MSL 1	
Resistance to Soldering Heat	MIL-STD-202, Method 210, Condition K	
Resistance to Solvents	MIL-STD-202, Method 215	
Solderability	MIL-STD-883, Method 2003 (Four I/O Pads on bottom of package only)	
Temperature Cycling	MIL-STD-883, Method 1010, Condition B	
Thermal Shock	MIL-STD-883, Method 1011, Condition B	
Vibration	MIL-STD-883, Method 2007, Condition A, 20G	



## **MECHANICAL DIMENSIONS (all dimensions in millimeters)**



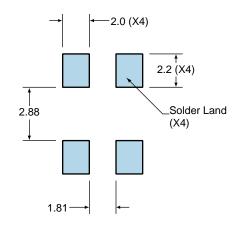
Note A: Center p	paddle is connected
	illator ground (Pad 2).

PIN	CONNECTION
1	Tri-State (High Impedance)
2	Ground
3	Output
4	Supply Voltage

# LINE MARKING 1 XXXX or XXXXX XXXX or XXXXX=Ecliptek Manufacturing Lot Code

#### **Suggested Solder Pad Layout**

All Dimensions in Millimeters



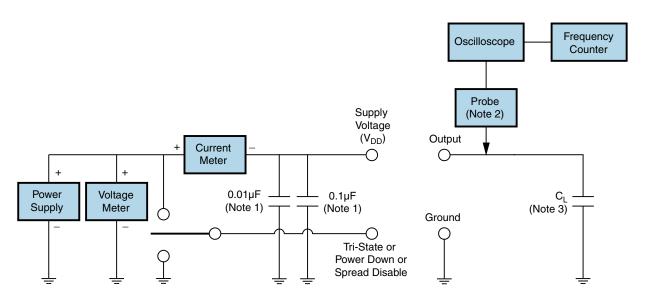
All Tolerances are ±0.1



#### **OUTPUT WAVEFORM & TIMING DIAGRAM**



#### **Test Circuit for CMOS Output**



Note 1: An external  $0.1\mu F$  low frequency tantalum bypass capacitor in parallel with a  $0.01\mu F$  high frequency ceramic bypass capacitor close to the package ground and  $V_{DD}$  pin is required.

Note 2: A low capacitance (<12pF), 10X attenuation factor, high impedance (>10Mohms), and high bandwidth (>300MHz) passive probe is recommended.

Note 3: Capacitance value  $\dot{C}_L$  includes sum of all probe and fixture capacitance.



# **Recommended Solder Reflow Methods**



## **High Temperature Infrared/Convection**

T <sub>S</sub> MAX to T <sub>L</sub> (Ramp-up Rate)	3°C/second Maximum
Preheat	
- Temperature Minimum (T <sub>s</sub> MIN)	150°C
- Temperature Typical (T <sub>s</sub> TYP)	175°C
- Temperature Maximum (T <sub>s</sub> MAX)	200°C
- Time (t <sub>s</sub> MIN)	60 - 180 Seconds
Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )	3°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	217°C
- Time (t∟)	60 - 150 Seconds
Peak Temperature (T <sub>P</sub> )	260°C Maximum for 10 Seconds Maximum
Target Peak Temperature (T <sub>P</sub> Target)	250°C +0/-5°C
Time within 5°C of actual peak (tp)	20 - 40 seconds
Ramp-down Rate	6°C/second Maximum
Time 25°C to Peak Temperature (t)	8 minutes Maximum
Moisture Sensitivity Level	Level 1



## **Recommended Solder Reflow Methods**



### Low Temperature Infrared/Convection 240°C

T <sub>S</sub> MAX to T <sub>L</sub> (Ramp-up Rate)	5°C/second Maximum
Preheat	
- Temperature Minimum (T <sub>s</sub> MIN)	N/A
- Temperature Typical (T <sub>S</sub> TYP)	150°C
- Temperature Maximum (T <sub>s</sub> MAX)	N/A
- Time (t <sub>s</sub> MIN)	60 - 120 Seconds
Ramp-up Rate (T <sub>L</sub> to T <sub>P</sub> )	5°C/second Maximum
Time Maintained Above:	
- Temperature (T∟)	150°C
- Time (t∟)	200 Seconds Maximum
Peak Temperature (T <sub>P</sub> )	240°C Maximum
Target Peak Temperature (T <sub>P</sub> Target)	240°C Maximum 1 Time / 230°C Maximum 2 Times
Time within 5°C of actual peak (tp)	10 seconds Maximum 2 Times / 80 seconds Maximum 1 Time
Ramp-down Rate	5°C/second Maximum
Time 25°C to Peak Temperature (t)	N/A
Moisture Sensitivity Level	Level 1

#### **Low Temperature Manual Soldering**

185°C Maximum for 10 seconds Maximum, 2 times Maximum.

#### **High Temperature Manual Soldering**

260°C Maximum for 5 seconds Maximum, 2 times Maximum.